AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s): Diane C. Boyd, et al.				Docket No. YOR920030335US1(16900)		
er No	Customer N	. G	Group Art Unit	Confirmation No.		
9	23389		1765	3237		
10/725,848 12-02-2003 Patricia Ann George 23389 1765 3237 Invention: ULTRA-THIN Si MOSFET DEVICE STRUCTURE AND METHOD OF MANUFACTURE						
COMMISSIONER FOR PATENTS:						
Transmitted herewith is an amendment in the above-identified application.						
The fee has been calculated and is transmitted as shown below.						
CLAIMS AS AMENDED						
	ER EXTRA	RATE	RATE	ADDITIONAL		
r	SPRESENT			FEE		
×	0		\$50.00 \$200.00	\$0.00 \$0.00		
×	0		φ200.00	\$0.00		
Multiple Dependent Claims (check if applicable) TOTAL ADDITIONAL FEE FOR THIS AMENDMENT \$0.00						
No additional fee is required for amendment. Please charge Deposit Account No. in the amount of A check in the amount of to cover the filing fee is enclosed. The Director is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account 50-0510/IBM Any additional filing fees required under 37 C.F.R. 1.16. Any patent application processing fees under 37 CFR 1.17. Payment by credit card. Form PTO-2038. WARNING: Information on this form may become public. Credit card information should not be included on this form. Provide credit card information and authorization on PTO-2038.						
Dated: December 20, 2006 I hereby certify that this correspondence is being deposited with the boited States Postal Service with sufficient postage as first class mains an envelope addressed to "Commissioner for Patents, P.O. Box 1450, Nexandria, VA 22313-1450" [37 CER 1.8(a)] on (Date) Signature of Person Mailing Correspondence						
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cc:

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: Diane C. Boyd et al.

Examiner: Patricia Ann George

Serial No:

10/725,848

Art Unit: 1765

Filed:

December 2, 2003

Docket:

YOR920030335US1(16900)

For:

ULTRA-THIN SI MOSFET

DEVICE STRUCTURE AND

METHOD OF MANUFACTURE

Dated:

December 20, 2006

Confirm. No. 3237

Mail Stop Amendment Commissioner for Patents United States Patent Office Alexandria, VA 23313-1450

RESPONSE UNDER 37 C.F.R. §1.111

Sir:

In response to the Office Action dated September 20, 2006, applicants submit the following remarks for entry of record in the above-identified patent application.

CERTIFICATE OF ELECTRONIC FILING

I hereby certify that this correspondence is being deposited with the United States Patent & Trademark Office via Electronic Filing through the United States Patent and Trademark Office e-business website, on December 20, 2006.

Dated: December 20, 2006

Leslie S. Szivos, Ph.D.